

# iscN-Channel MOSFET Transistor

# IRFP21N60L

### • FEATURES

- Low drain-source on-resistance: R<sub>DS</sub>(ON) =0.32Ω (MAX)
- Enhancement mode:
  Vth = 3.0 to 5.0V (Vps = 10 V, Ip=0.25mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

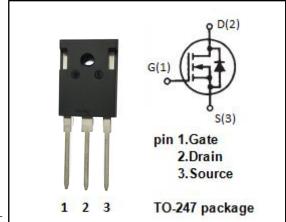
· Switching Voltage Regulators

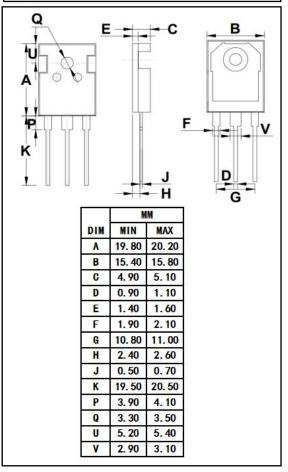
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	600	V
V <sub>GS</sub>	Gate-Source Voltage	±30	V
lσ	Drain Current-Continuous	21	Α
Ірм	Drain Current-Single Pulsed	84	Α
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	330	W
Tj	Max. Operating Junction Temperature	ax. Operating Junction Temperature -55~150	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}\!\mathbb{C}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.38	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =0.25mA	3.0		5.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =13A			0.32	Ω
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =600V; V <sub>GS</sub> = 0V V <sub>DS</sub> =480V; V <sub>GS</sub> = 0V;T <sub>J</sub> =125℃			0.05 2.0	mA
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =21A, V <sub>GS</sub> = 0 V			1.5	V

#### **NOTICE:**

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